TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

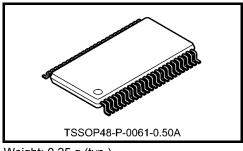
TC74VCXHR162245FT

Low-Voltage 16-Bit Bus Transceiver with Bushold

The TC74VCXHR162245FT is a high-performance CMOS 16-bit bus transceiver. Designed for use in 1.8-V, 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This 16-bit bus transceiver is controlled by direction control (DIR) inputs and output enable ($\overline{\text{OE}}$) inputs which are common to each byte. It can be used as two 8-bit transceivers or one 16-bit transceiver. The direction of data transmission is determined by the level of the DIR inputs. The $\overline{\text{OE}}$ inputs can be used to disable the device so that the busses are effectively isolated.

The 26- Ω series resistor helps reducing output overshoot and undershoot without external resistor.



Weight: 0.25 g (typ.)

The A, B data inputs include active bushold circuitry, eliminating the need for external pull-up resistors to hold unused or floating data inputs at a valid logic level.

All inputs are equipped with protection circuits against static discharge.

Features (Note)

- 26-Ω series resistors on all outputs
- Low-voltage operation: V_{CC} = 1.8 to 3.6 V
- Bushold on data inputs eliminating the need for external pull-up/pull-down resistors
- High-speed operation: t_{pd} = 3.4 ns (max) (V_{CC} = 3.0 to 3.6 V)

: t_{pd} = 4.3 ns (max) (V_{CC} = 2.3 to 2.7 V)

: t_{pd} = 5.7 ns (max) (V_{CC} = 1.8 V)

- 3.6-V tolerant control inputs.
- Output current: $I_{OH}/I_{OL} = \pm 12 \text{ mA} \text{ (min)} (V_{CC} = 3.0 \text{ V})$

$$: I_{OH}/I_{OL} = \pm 8 \text{ mA (min)} (V_{CC} = 2.3 \text{ V})$$

$$: I_{OH}/I_{OL} = \pm 4 \text{ mA (min)} (V_{CC} = 1.8 \text{ V})$$

- Latch-up performance: -300 mA
- ESD performance: Machine model $\geq \pm 200 \text{ V}$
 - Human body model $\ge \pm 2000 \text{ V}$
- Package: TSSOP

Note: Do not apply a signal to any bus pins when it is in the output mode. Damage may result.

Pin Assignment (top view)

	1		1	
1DIR	1	\bigcirc	48	10E
1B1	2		47	1A1
1B2	3		46	1A2
GND	4		45	GND
1B3	5		44	1A3
1B4	6		43	1A4
V _{CC}	7		42	V _{CC}
1B5	8		41	1A5
1B6	9		40	1A6
GND	10		39	GND
1B7	11		38	1A7
1B8	12		37	1A8
2B1	13		36	2A1
2B2	14		35	2A2
GND	15		34	GND
2B3	16		33	2A3
2B4	17		32	2A4
V _{CC}	18		31	V _{CC}
2B5	19		30	2A5
2B6	20		29	2A6
GND	21		28	GND
2B7	22		27	2A7
2B8	23		26	2A8
2DIR	24		25	20E
			I	

IEC Logic Symbol

10E - 1DIR - 20E - 2DIR -	48 G3 1 G3 3 EN1 (BA) 3 EN2 (AB) 25 G6 24 6 EN4 (BA) 6 EN5 (AB)	
1A1 -		1B1
1A2 - 1A3 - 1A4 - 1A5 - 1A6 - 1A7 - 1A8 - 2A1 -	$46 \qquad \qquad$	1B2 1B3 1B4 1B5 1B6 1B7 1B8 2B1
2A2 - 2A3 - 2A4 - 2A5 - 2A6 - 2A7 -	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	2B2 2B3 2B4 2B5 2B6 2B7
2A8 -	$26 \leftrightarrow 23 2$	2B8

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Truth Table

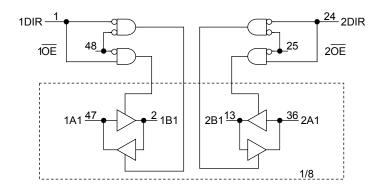
Inp	outs	Fund			
10E	1DIR	Bus 1A1-1A8	Bus 1B1-1B8	Outputs	
L	L	Output	Input	A = B	
L	Н	Input	Output	B = A	
Н	Х	Z		Z	

Inp	Inputs		ction			
20E	2DIR	BUS 2A1-2A8	BUS 2B1-2B8	Outputs		
L	L	Output	Input	A = B		
L	Н	Input	Output	B = A		
Н	Х	Z		Z		

X: Don't care

Z: High impedance

System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics		Symbol	Rating	Unit
Power supply voltage		V _{CC}	-0.5 to 4.6	V
	(DIR, OE)		-0.5 to 4.6	
DC input voltage	(An, Bn)	V _{IN}	–0.5 to V _{CC} + 0.5 (Note 2)	V
DC output voltage	(An, Bn)	V _{OUT}	-0.5 to V _{CC} + 0.5 (Note 3)	V
Input diode current		IIК	-50	mA
Output diode current		IOK	±50 (Note 4)	mA
Output current		IOUT	±50	mA
Power dissipation		PD	400	mW
DC V _{CC} /ground curren	t per supply pin	I _{CC} /I _{GND}	±100	mA
Storage temperature		T _{stg}	–65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 2: OFF state
- Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Operating Ranges (Note 1) (Note 2)

Characteristics		Symbol	Rating	Unit	
Power supply voltage		V _{CC}	1.8 to 3.6	V	
Power supply voltage		VCC	1.2 to 3.6 (Note 3)	v	
Input voltage	(DIR, OE)	Max	-0.3 to 3.6	V	
input voltage	(An, Bn)	V _{IN}	0 to V _{CC} (Note 4)	V	
Output voltage	(An, Bn)	V _{OUT}	0 to V _{CC} (Note 5)	V	
			±12 (Note 6)		
Output current		I _{OH} /I _{OL}	±8 (Note 7)	mA	
			±4 (Note 8)		
Operating temperature		T _{opr}	-40 to 85	°C	
Input rise and fall time		dt/dv	0 to 10 (Note 9)	ns/V	

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs and bus inputs must be tied to either V_{CC} or GND. Please connect both bus inputs and the bus outputs with V_{CC} or GND when the I/O of the bus terminal changes by the function. In this case, please note that the output is not short-circuited.

- Note 2: Floating or unused control inputs must be held high or low.
- Note 3: Data retention only
- Note 4: OFF state
- Note 5: High or low state
- Note 6: $V_{CC} = 3.0$ to 3.6 V
- Note 7: V_{CC} = 2.3 to 2.7 V
- Note 8: V_{CC} = 1.8 V
- Note 9: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V

Electrical Characteristics

DC Characteristics (Ta = -40 to 85°C, 2.7 V < V_{CC} \leq 3.6 V)

Characte	viction	Cymrain al	Test	Na maliki a m		Min	Мах	Unit
Characte	IISUCS	Symbol	Test Condition		V _{CC} (V)	IVIIII	Wax	Unit
Input voltage	H-level	VIH		_	2.7 to 3.6	2.0		V
input voltage	L-level	VIL			2.7 to 3.6		0.8	v
				I _{OH} = -100 μA	2.7 to 3.6	V _{CC} - 0.2	—	
	H-level	Vон	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -6 mA	2.7	2.2		
				$I_{OH} = -8 \text{ mA}$	3.0	2.4	_	
Output voltage				$I_{OH} = -12 \text{ mA}$	3.0	2.2	_	V
				I _{OL} = 100 μA	2.7 to 3.6	_	0.2	
L-level	Vol	VIN = VIH or VIL	I _{OL} = 6 mA	2.7	_	0.4		
	L-level	VOL	AIV = AIH OL AIT	I _{OL} = 8 mA	3.0	_	0.5	
				I _{OL} = 12 mA	3.0	_	0.8	
Input leakage curr (DIR, OE)	ent	I _{IN}	$V_{IN} = 0$ to 3.6 V		2.7 to 3.6		±5.0	μA
Bushold input min	imum drive		V _{IN} = 0.8 V		3.0	75		•
hold current		II (HOLD)	V _{IN} = 2.0 V		3.0	-75		μA
Bushold input ove	r-drive current		V _{IN} = "L"→"H"		3.6		450	•
to change state (N	lote)	II (OD)	V _{IN} = "H"→"L"		3.6	_	-450	μA
3-state output OFF	= state current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or } GND$		2.7 to 3.6		±10.0	μA
Quiescent supply	current	ICC	$V_{IN} = V_{CC}$ or GND		2.7 to 3.6	_	20.0	μA
Increase in I _{CC} pe	er input	∆lcc	$V_{IH} = V_{CC} - 0.6 V$		2.7 to 3.6		750	μA

Note: It is a necessary electric current to change the input in "L" or "H".

DC Characteristics (Ta = -40 to 85° C, 2.3 V \leq V_{CC} \leq 2.7 V)

Character	istics	Symbol	Test	Condition	V _{CC} (V)	Min	Max	Unit
	H-level	VIH		_	2.3 to 2.7	1.6	_	V
Input voltage	L-level	VIL		_	2.3 to 2.7		0.7	v
				I _{OH} = -100 μA	2.3 to 2.7	V _{CC} - 0.2	_	
	H-level	Vон	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -4 mA	2.3	2.0		
				I _{OH} = -6 mA	2.3	1.8	_	
Output voltage				I _{OH} = -8 mA	2.3	1.7	_	V
		V _{OL}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 100 μA	2.3 to 2.7	_	0.2	
	L-level			I _{OL} = 6 mA	2.3		0.4	
				I _{OL} = 8 mA	2.3		0.6	
Input leakage curre (DIR, \overline{OE})	ent	I _{IN}	$V_{IN} = 0$ to 3.6 V		2.3 to 2.7	_	±5.0	μA
Bushold input minir	num drive		V _{IN} = 0.7 V		2.3	45		^
hold current		II (HOLD)	V _{IN} = 1.6 V		2.3	-45		μA
Bushold input over-	-drive current		V _{IN} = "L"→"H"		2.7		300	•
to change state (No	ote)	I _{I (OD)}	V _{IN} = "H"→"L"		2.7		-300	μA
3-state output OFF	state current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or } GND$		2.3 to 2.7		±10.0	μΑ
Quiescent supply c	urrent	ICC	$V_{IN} = V_{CC}$ or GND		2.3 to 2.7	_	20.0	μA

Note: It is a necessary electric current to change the input in "L" or "H".

DC Characteristics (Ta = -40 to 85° C, 1.8 V \leq V_{CC} < 2.3 V)

Characteri	stics	Symbol	Test	Test Condition		Min	Max	Unit
	H-level	V _{IH}			V _{CC} (V) 1.8 to 2.3	0.7 × V _{CC}		
Input voltage	L-level	VIL			1.8 to 2.3		$0.2 \times V_{CC}$	V
	H-level	Vон	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = -100 μA	1.8	V _{CC} - 0.2	_	
Output voltage	Dutput voltage	011		I _{OH} = -4 mA	1.8	1.4	_	V
		I _{OL} = 100 μA		1.8	_	0.2	1	
	L-level	V _{OL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OL} = 4 mA	1.8	8 —		
Input leakage currer (DIR, OE)	nt	I _{IN}	$V_{IN} = 0$ to 3.6 V		1.8		±5.0	μΑ
Bushold input minin	num drive		V _{IN} = 0.36 V		1.8	25		٨
hold current		II (HOLD)	V _{IN} = 1.26 V		1.8	-25		μA
Bushold input over-	drive current		V _{IN} = "L"→"H"		1.8		200	•
to change state (Note)		II (OD)	V _{IN} = "H"→"L"		1.8		-200	μA
3-state output OFF	state current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or } GND$		1.8		±10.0	μΑ
Quiescent supply cu	urrent	ICC	$V_{IN} = V_{CC}$ or GND		1.8	_	20.0	μA

Note: It is a necessary electric current to change the input in "L" or "H".

AC Characteristics (Ta = -40 to 85°C, input: $t_r = t_f = 2.0 \text{ ns}$, $C_L = 30 \text{ pF}$, $R_L = 500 \Omega$) (Note 1)

Characteristics	Symbol	Test Condition		Min	Мах	Unit
	Cymbol		$V_{CC}(V)$	WIIIT	Max	0
	t		1.8	1.5	5.7	
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.5 ± 0.2	1.0	4.3	ns
	t _{pHL}		$\textbf{3.3}\pm\textbf{0.3}$	0.8	3.4	
3-state output enable time	.		1.8	1.5	7.6	
	t _{pZL} t _{pZH}	Figure 1, Figure 3	2.5 ± 0.2	1.0	5.7	ns
			$\textbf{3.3}\pm\textbf{0.3}$	0.8	4.2	
	• . –		1.8	1.5	5.7	
3-state output disable time	t _{pLZ}	Figure 1, Figure 3	2.5 ± 0.2	1.0	4.8	ns
	^t pHZ		$\textbf{3.3}\pm\textbf{0.3}$	0.8	4.1	
			1.8	_	0.5	
Output to output skew	t _{osLH}	(Note 2)	2.5 ± 0.2	_	0.5	ns
	t _{osHL}		$\textbf{3.3}\pm\textbf{0.3}$		0.5	

Note 1: For $C_L = 50 \text{ pF}$, add approximately 300 ps to the AC maximum specification.

Note 2: Parameter guaranteed by design. $(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$

Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.0 \text{ ns}$, $C_L = 30 \text{ pF}$)

Characteristics	Symbol	Test Condition			Тур.	Unit	
	-			$V_{CC}\left(V\right)$			
		$V_{IH} = 1.8 V, V_{IL} = 0 V$	(Note)	1.8	0.15		
Quiet output maximum dynamic V _{OL}	V _{OLP}	$V_{IH} = 2.5 V, V_{IL} = 0 V$	(Note)	2.5	0.25	V	
		$V_{IH} = 3.3 V, V_{IL} = 0 V$	(Note)	3.3	0.35		
		$V_{IH} = 1.8 V, V_{IL} = 0 V$	(Note)	1.8	-0.15		
Quiet output minimum dynamic V _{OI}	V _{OLV}	$V_{IH} = 2.5 V, V_{IL} = 0 V$	(Note)	2.5	-0.25	V	
,		$V_{IH} = 3.3 V, V_{IL} = 0 V$	(Note)	3.3	-0.35		
		$V_{IH} = 1.8 V, V_{IL} = 0 V$	(Note)	1.8	1.55		
Quiet output minimum dynamic V _{OH}	V _{OHV}	$V_{IH} = 2.5 V, V_{IL} = 0 V$	(Note)	2.5	2.05	5 V	
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	(Note)	3.3	2.65		

Note: Parameter guaranteed by design.

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	_		Тур.	Unit
Characteristics	Symbol			V _{CC} (V)	тур.	
Input capacitance	C _{IN}			1.8, 2.5, 3.3	6	pF
Bus I/O capacitance	C _{I/O}			1.8, 2.5, 3.3	7	pF
Power dissipation capacitance	C _{PD}	$f_{IN} = 10 \text{ MHz}$ (N	lote)	1.8, 2.5, 3.3	20	pF

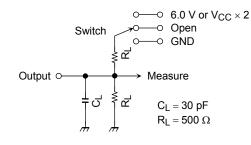
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/16$ (per bit)

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AC Test Circuit



Parameter	Switch		
t _{pLH} , t _{pHL}	Open		
t _{pLZ} , t _{pZL}			
t _{pHZ} , t _{pZH}	GND		



AC Waveform

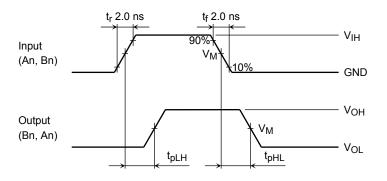


Figure 2 tpLH, tpHL

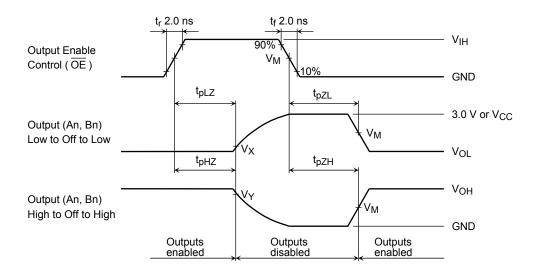


Figure 3 $t_{pLZ}, t_{pHZ}, t_{pZL}, t_{pZH}$

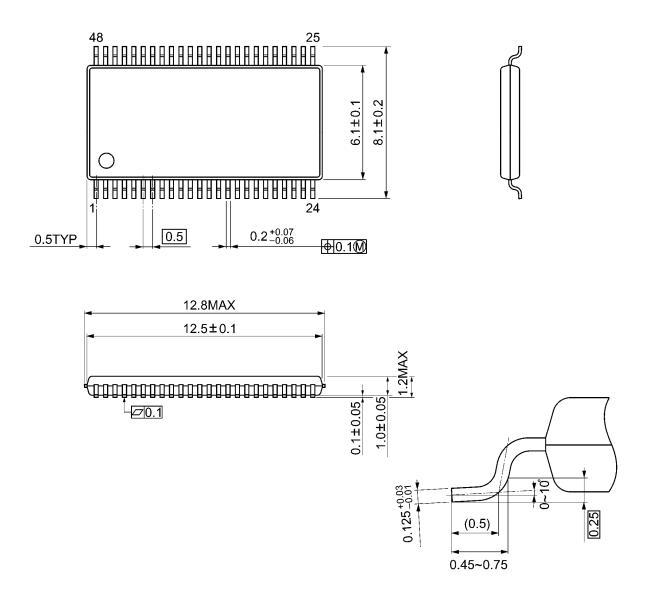
Symbol	V _{CC}		
	$3.3\pm0.3~V$	$2.5\pm0.2~V$	1.8 V
VIH	2.7 V	V _{CC}	V _{CC}
VM	1.5 V	V _{CC} /2	V _{CC} /2
VX	V _{OL} + 0.3 V	V _{OL} + 0.15 V	V _{OL} + 0.15 V
VY	V _{OH} – 0.3 V	V _{OH} – 0.15 V	V _{OH} – 0.15 V



Package Dimensions

TSSOP48-P-0061-0.50A

Unit: mm



Weight: 0.25 g (typ.)

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